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FAIRCHILD

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MM74HC245A Octal 3-STATE Transceiver

General Description

The MM74HC245A 3-STATE bidirectional buffer utilizes advanced silicon-gate CMOS technology, and is intended for two-way asynchronous communication between data buses. It has high drive current outputs which enable high speed operation even when driving large bus capacitances. This circuit possesses the low power consumption and high noise immunity usually associated with CMOS circuitry, yet has speeds comparable to low power Schottky TTL circuits.

This device has an active LOW enable input \overline{G} and a direction control input, DIR. When DIR is HIGH, data flows from the A inputs to the B outputs. When DIR is LOW, data flows from the B inputs to the A outputs. The MM74HC245A transfers true data from one bus to the other.

This device can drive up to 15 LS-TTL Loads, and does not have Schmitt trigger inputs. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical propagation delay: 13 ns
- Wide power supply range: 2–6V
- Low quiescent current: 80 μA maximum (74 HC)
- 3-STATE outputs for connection to bus oriented systems
- High output drive: 6 mA (minimum)

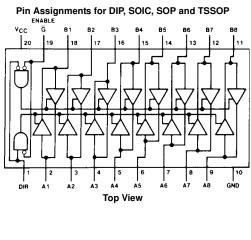
Same as the 645

Ordering Code:

| Order Number Package Number | | Package Description | | | |
|-----------------------------|-------|---|--|--|--|
| MM74HC245AWM | M20B | 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide | | | |
| MM74HC245ASJ | M20D | 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide | | | |
| MM74HC245AMTC | MTC20 | 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide | | | |
| MM74HC245AN | N20A | 20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide | | | |

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

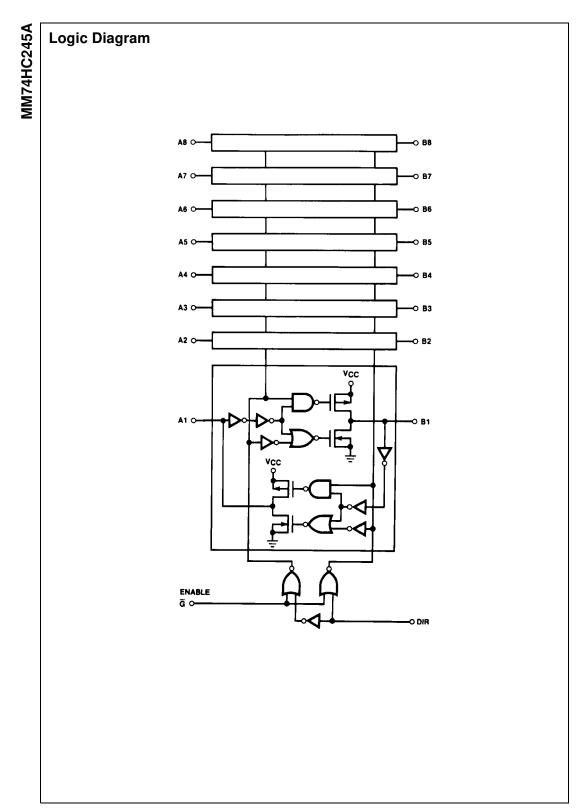


| Co | ntrol | | | |
|-----|-------|-----------------|--|--|
| Inp | outs | Operation | | |
| G | DIR | | | |
| L | L | B data to A bus | | |
| L | н | A data to B bus | | |
| н | х | Isolation | | |

H = HIGH Level L = LOW Level X = Irrelevant

Truth Table

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2

Absolute Maximum Ratings(Note 1)

| Recommended Operating |
|------------------------------|
| Conditions |

| | • |
|---|-------------------------------|
| (Note 2) | |
| Supply Voltage (V _{CC}) | -0.5 to +7.0V |
| DC Input Voltage DIR and \overline{G} pins (V _{IN}) | –1.5 to V_{CC} +1.5V |
| DC Input/Output Voltage (V _{IN} , V _{OUT}) | –0.5 to V _{CC} +0.5V |
| Clamp Diode Current (I _{CD}) | ±20 mA |
| DC Output Current, per pin (I _{OUT}) | ±35 mA |
| DC V _{CC} or GND Current, per pin (I _{CC}) | ±70 mA |
| Storage Temperature Range (T _{STG}) | –65°C to +150°C |
| Power Dissipation (P _D) | |
| (Note 3) | 600 mW |
| S.O. Package only | 500 mW |
| Lead Temperature (TL) | |
| (Soldering 10 seconds) | 260°C |
| | |

| | Min | Max | Units | | |
|---|-----|-----------------|-------|--|--|
| Supply Voltage (V _{CC}) | 2 | 6 | V | | |
| DC Input or Output Voltage | | | | | |
| (V _{IN} , V _{OUT}) | 0 | V _{CC} | V | | |
| Operating Temperature Range (T _A) | -40 | +85 | °C | | |
| Input Rise/Fall Times | | | | | |
| $(t_r, t_f) V_{CC} = 2.0V$ | | 1000 | ns | | |
| $V_{CC} = 4.5V$ | | 500 | ns | | |
| V _{CC} = 6.0V 400 ns | | | | | |
| Note 1: Maximum Ratings are those values beyond which damage to the device may occur. | | | | | |

MM74HC245A

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

| Symbol | Parameter | Conditions | Vcc | $T_A = 25^{\circ}C$ | | $T_A=-40$ to $85^\circ C$ | $T_A = -55$ to 125°C | Units | |
|-----------------|---------------------------|--|------|---------------------|--------------|---------------------------|----------------------|-------|--|
| Symbol | | | *cc | Тур | Guaranteed I | | imits | Units | |
| VIH | Minimum HIGH Level Input | | 2.0V | | 1.5 | 1.5 | 1.5 | V | |
| | Voltage | | 4.5V | | 3.15 | 3.15 | 3.15 | V | |
| | | | 6.0V | | 4.2 | 4.2 | 4.2 | V | |
| V _{IL} | Maximum LOW Level Input | | 2.0V | | 0.5 | 0.5 | 0.5 | V | |
| | Voltage | | 4.5V | | 1.35 | 1.35 | 1.35 | V | |
| | | | 6.0V | | 1.8 | 1.8 | 1.8 | V | |
| V _{OH} | Minimum HIGH Level Output | V _{IN} = V _{IH} or V _{IL} | | | | | | | |
| | Voltage | $ I_{OUT} \le 20 \ \mu A$ | 2.0V | 2.0 | 1.9 | 1.9 | 1.9 | v | |
| | | | 4.5V | 4.5 | 4.4 | 4.4 | 4.4 | V | |
| | | | 6.0V | 6.0 | 5.9 | 5.9 | 5.9 | V | |
| | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | | | | | | |
| | | $ I_{OUT} \le 6.0 \text{ mA}$ | 4.5V | 4.2 | 3.98 | 3.84 | 3.7 | V | |
| | | I _{OUT} ≤ 7.8 mA | 6.0V | 5.7 | 5.48 | 5.34 | 5.2 | V | |
| V _{OL} | Maximum LOW Level Output | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | | | | | | |
| | Voltage | $ I_{OUT} \le 20 \ \mu A$ | 2.0V | 0 | 0.1 | 0.1 | 0.1 | V | |
| | | | 4.5V | 0 | 0.1 | 0.1 | 0.1 | V | |
| | | | 6.0V | 0 | 0.1 | 0.1 | 0.1 | V | |
| | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | | | | | | |
| | | $ I_{OUT} \le 6.0 \text{ mA}$ | 4.5V | 0.2 | 0.26 | 0.33 | 0.4 | V | |
| | | $ I_{OUT} \le 7.8 \text{ mA}$ | 6.0V | 0.2 | 0.26 | 0.33 | 0.4 | V | |
| I _{IN} | Input Leakage | V _{IN} = V _{CC} to GND | 6.0V | | ±0.1 | ±1.0 | ±1.0 | μA | |
| | Current (G and DIR) | | | | | | | | |
| l _{oz} | Maximum 3-STATE Output | $V_{OUT} = V_{CC}$ or GND | 6.0V | | ±0.5 | ±5.0 | ±10 | μA | |
| | Leakage Current | Enable $\overline{G} = V_{IH}$ | | | | | | | |
| I _{CC} | Maximum Quiescent Supply | V _{IN} = V _{CC} or GND | 6.0V | | 8.0 | 80 | 160 | μA | |
| | Current | I _{OUT} = 0 μA | | | | | | | |

DC Electrical Characteristics (Note 4)

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

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AC Electrical Characteristics

 $V_{CC} = 5V, T_A = 25^{\circ}C, t_r = t_f = 6ns$

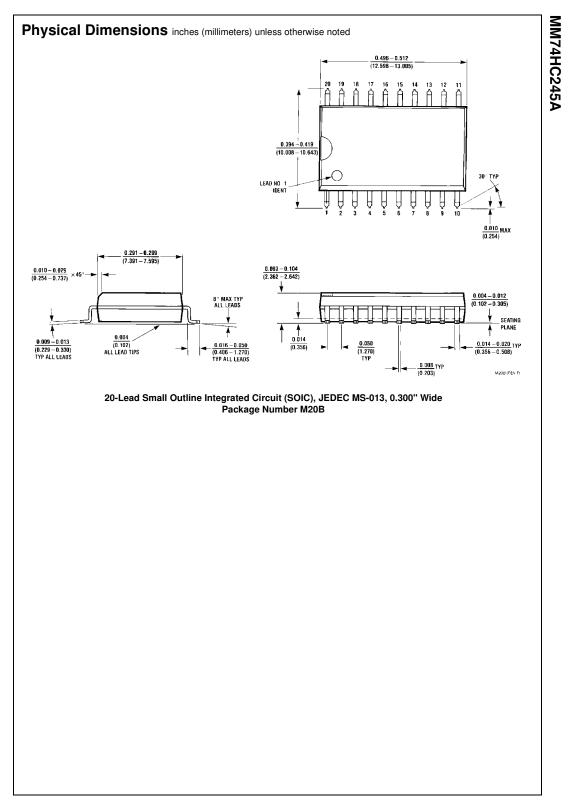
| 100 01, 14 | $(-200, t_{f} - t_{f} = 0.03)$ | | | | |
|-------------------------------------|--------------------------------|-----------------------|-----|---------------------|-------|
| Symbol | Parameter | Conditions | Тур | Guaranteed Limit | Units |
| t _{PHL} , t _{PLH} | Maximum Propagation Delay | $C_L = 45 \text{ pF}$ | 12 | 17 | ns |
| t _{PZH} , t _{PZL} | Maximum Output Enable | $R_L = 1 \ k\Omega$ | 24 | 35 | ns |
| | Time | $C_L = 45 \text{ pF}$ | | | |
| t _{PHZ} , t _{PLZ} | Maximum Output Disable | $R_L = 1 k\Omega$ | 18 | 25 | ns |
| | Time | $C_L = 5 \text{ pF}$ | | | |

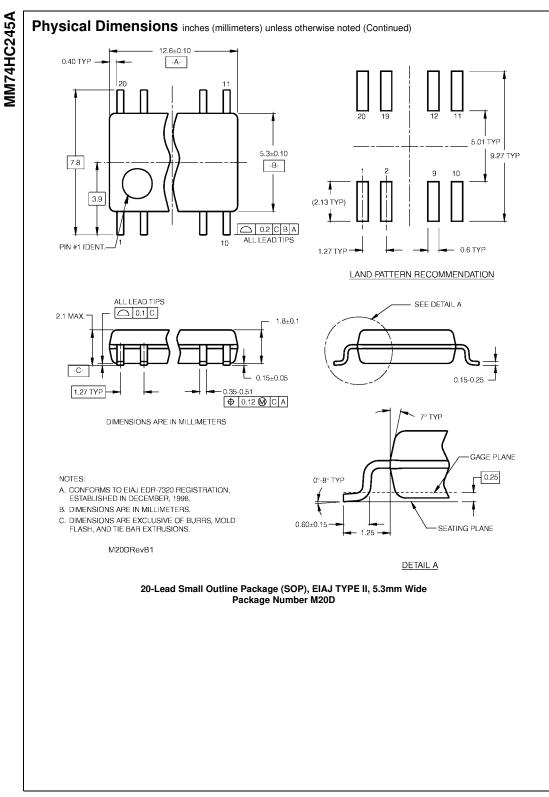
AC Electrical Characteristics

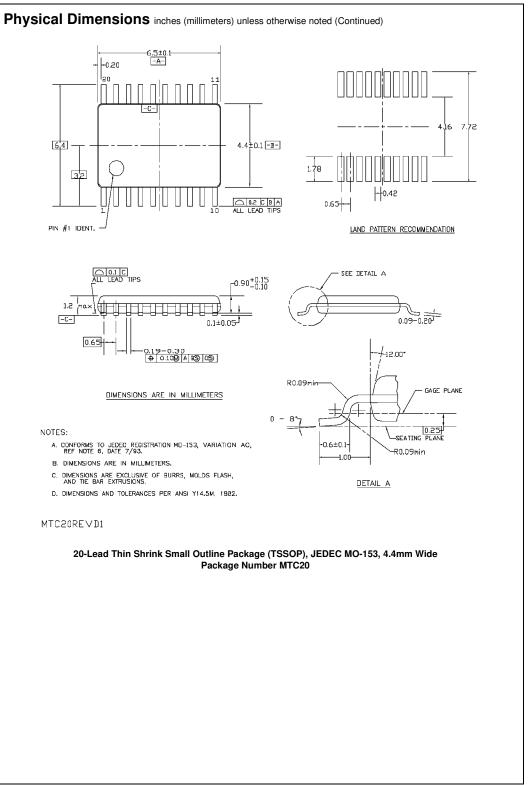
 v_{CC} = 2.0V to 6.0V, C_L = 50 pF, t_r = t_f = 6ns (unless otherwise specified)

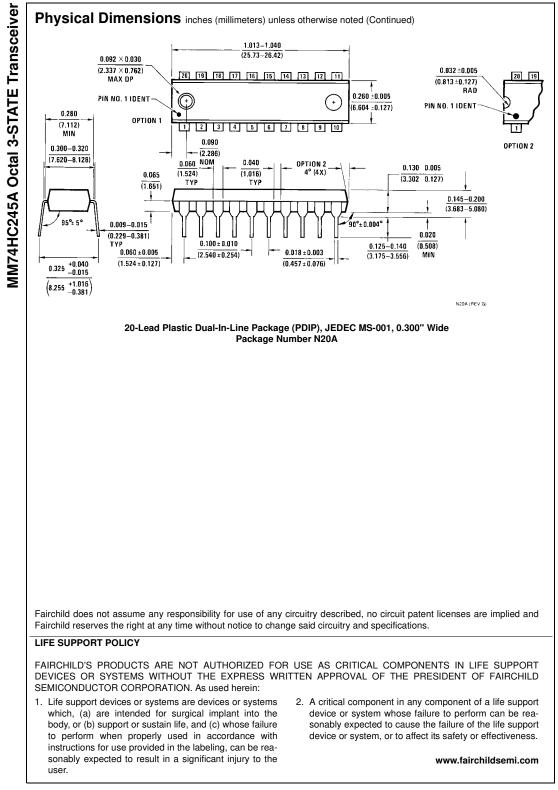
| Symbol | Parameter | Conditions | v _{cc} | T _A = 25°C | | $T_A = -40$ to $85^{\circ}C$ | $T_A = -55$ to $125^{\circ}C$ | Units |
|-------------------------------------|---------------------------|-------------------------|-----------------|-----------------------|-----|------------------------------|-------------------------------|-------|
| Symbol | | | | Тур | | Guaranteed L | Guaranteed Limits | |
| t _{PHL} , | Maximum Propagation | C _L = 50 pF | 2.0V | 31 | 90 | 113 | 135 | ns |
| t _{PLH} | Delay | $C_L = 150 \text{ pF}$ | 2.0V | 41 | 96 | 116 | 128 | ns |
| | | C _L = 50 pF | 4.5V | 13 | 18 | 23 | 27 | ns |
| | | $C_L = 150 \text{ pF}$ | 4.5V | 17 | 22 | 28 | 33 | ns |
| | | $C_L = 50 \text{ pF}$ | 6.0V | 11 | 15 | 19 | 23 | ns |
| | | $C_L = 150 \text{ pF}$ | 6.0V | 14 | 19 | 23 | 28 | ns |
| t _{PZH} , | Maximum Output Enable | $R_L = 1 k\Omega$ | | | | | | |
| t _{PZL} | Time | C _L = 50 pF | 2.0V | 71 | 190 | 240 | 285 | ns |
| | | $C_L = 150 \text{ pF}$ | 2.0V | 81 | 240 | 300 | 360 | ns |
| | | $C_L = 50 \text{ pF}$ | 4.5V | 26 | 38 | 48 | 57 | ns |
| | | C _L = 150 pF | 4.5V | 31 | 48 | 60 | 72 | ns |
| | | $C_L = 50 \text{ pF}$ | 6.0V | 21 | 32 | 41 | 48 | ns |
| | | $C_L = 150 \text{ pF}$ | 6.0V | 25 | 41 | 51 | 61 | ns |
| t _{PHZ} , | Maximum Output Disable | $R_L = 1 k\Omega$ | 2.0V | 39 | 135 | 169 | 203 | ns |
| t _{PLZ} | Time | $C_L = 50 \text{ pF}$ | 4.5V | 20 | 27 | 34 | 41 | ns |
| | | | 6.0V | 18 | 23 | 29 | 34 | ns |
| t _{TLH} , t _{THL} | Output Rise and Fall Time | C _L =50 pF | 2.0V | 20 | 60 | 75 | 90 | ns |
| | | | 4.5V | 6 | 12 | 15 | 18 | ns |
| | | | 6.0V | 5 | 10 | 13 | 15 | ns |
| C _{PD} | Power Dissipation | $\overline{G} = V_{IL}$ | | 50 | | | | pF |
| | Capacitance (Note 5) | $\overline{G} = V_{IH}$ | | 5 | | | | pF |
| C _{IN} | Maximum Input Capacitance | | | 5 | 10 | 10 | 10 | pF |
| C _{IN/OUT} | Maximum Input/Output | | | 15 | 20 | 20 | 20 | pF |
| | Capacitance, A or B | | | | | | | |

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2$ f+I_{CC} V_{CC} , and the no load dynamic current consumption, $I_S = C_{PD} V_{CC}$ f+I_{CC}.









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